

Citations for Target : **HgCdTe**

<i>Pub. Year</i>	<i>Authors, Title, Journal Citation and Comments</i>	<i>Citation Numb</i>
1988	Wilson, R. G. '(111) Random and (110) Channeling Implantation Profiles and Range Parameters in HgCdTe' <i>J. Appl. Phys., 63, 5302-5311 (1988)</i> Comment : R, dR. 45 Ions (H to Ta) at 100-700 keV -> HgCdTe	1988-Wils 1397
1988	Wilson, R. G. 'Ion Implantation and SIMS Profiling of Impurities in II-VI Materials HgCdTe and CdTe' <i>J. Crystal Growth, 86, 735-743 (1988)</i> Comment : R, dR. 52 Ions (H-Hg) at 100-700 keV -> CdTe, HgCdTe	1988-Wils2 1445